

# 1A, 50V - 1000V Glass Passivated Rectifier

#### **FEATURES**

- Glass passivated chip junction
- High current capability, Low VF
- High reliability
- High surge current capability
- Low power loss, high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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- Switching mode power supply (SMPS)
- Adapters
- TV
- Monitor

#### **MECHANICAL DATA**

- Case: DO-204AL (DO-41)
- Molding compound meets UL 94V-0 flammability rating
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 0.33 g (approximately)

KEY PARAMETERS						
PARAMETER	VALUE	UNIT				
I <sub>F(AV)</sub>	1	Α				
$V_{RRM}$	50 - 1000	<b>V</b>				
I <sub>FSM</sub>	30	Α				
T <sub>J MAX</sub>	150 °C					
Package	DO-204AL (DO-41)					
Configuration	Single Die					





DO-204AL (DO-41)

PARAMETER	CVMDOI	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	UNIT
PARAMETER	SYMBOL	G-K	G-K	G-K	G-K	G-K	G-K	G-K	
Marking code on the device		1N4001G	1N4002G	1N4003G	1N4004G	1N4005G	1N4006G	1N4007G	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Forward current	I <sub>F(AV)</sub>				1				Α
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>				30				А
Junction temperature	$T_J$	- 55 to +150					°C		
Storage temperature	T <sub>STG</sub>				55 to +150				°C

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THERMAL PERFORMANCE								
PARAMETER	SYMBOL	LIMIT	TINU					
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	80	°C/W					

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)							
PARAMETER	CONDITIONS	SYMBOL	TYP	МАХ	UNIT		
Forward voltage per diode (1)	I <sub>F</sub> = 1A,T <sub>J</sub> = 25°C	$V_{F}$	-	1	V		
	T <sub>J</sub> = 25°C		-	5	μA		
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>	T <sub>J</sub> = 125°C	I <sub>R</sub>	-	100	μA		
Junction capacitance	1 MHz, V <sub>R</sub> =4.0V	CJ	10	-	pF		

### Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION							
PART NO.	PACKIN G CODE	PACKING CODE SUFFIX	PACKAGE	PACKING			
	A0	G	DO-41	3,000 / Ammo box (52mm taping)			
1N400xG-K	R0		DO-41	5,000 / 13" Paper reel			
(Note 1, 2)	R1		DO-41	5,000 / 13" Paper reel (Reverse)			
	В0		DO-41	1,000 / Bulk packing			

### Notes:

- 1. "x" defines voltage from 50V (1N4001G-K) to 1000V (1N4007G-K)
- 2. Whole series with green compound (halogen-free)

EXAMPLE P/N							
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION			
1N4001G-K A0G	1N4001G-K	A0	G	Green compound			



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig1. Forward Current Derating Curve

0.5 0 25 50 75 100 125 150 AMBIENT TEMPERATURE(°C)

Fig2. Typical Junction Capacitance

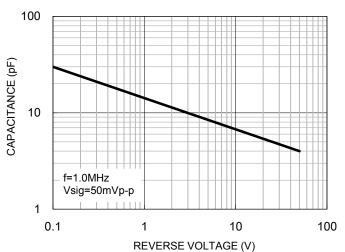


Fig3. Typical Reverse Characteristics

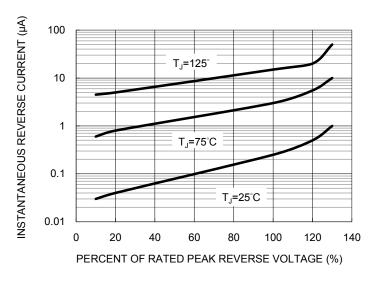
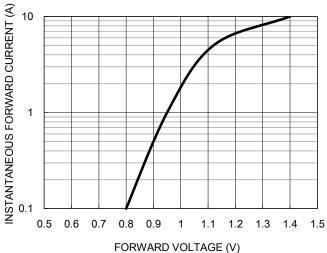


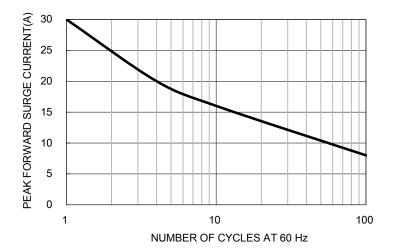
Fig4. Typical Forward Characteristics



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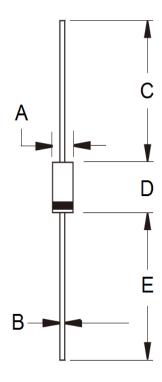
Fig5. Maximum Non-repetitive Forward Surge Current





## **PACKAGE OUTLINE DIMENSIONS**

DO-204AL (DO-41)



DIM.	Unit (ı	nm)	Unit (inch)		
DIWI.	Min	Max	Min	Max	
Α	2.00	2.70	0.079	0.106	
В	0.71	0.86	0.028	0.034	
С	25.40	-	1.000	-	
D	4.20	5.20	0.165	0.205	
E	25.40	-	1.000	-	

## **MARKING DIAGRAM**



= Marking Code= Green Compound P/N G YWW = Date Code = Factory Code



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